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STATEMENT BY APPLICANT**  
( Not for submission under 37 CFR 1.99)

Application Number	10594934
Filing Date	2007-10-29
First Named Inventor	Szeles
Art Unit	1752
Examiner Name	Not Yet Assigned
Attorney Docket Number	4375-062621

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	8	BARNES and ZANIO, Photoluminescence in high-resistivity CdTe:In, Journal of Applied Physics, September 1975, pages 3959-3964, Volume 46, No. 9, American Institute of Physics	<input type="checkbox"/>
	9	KUHN et al., Evidence of deep donor in CdTe, Journal of Crystal Growth, 1992, pages 660-665, Volume 117, Elsevier Science Publishers B.V.	<input type="checkbox"/>

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10	SETO et al., Chlorine-related photoluminescence lines in high-resistivity Cl-doped CdTe, Journal of Crystal Growth, pages 271-275, Volume 117, Elsevier Science Publishers B.V.	<input type="checkbox"/>
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